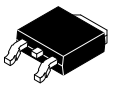
1.0 A Low-Dropout Positive Fixed and Adjustable Voltage Regulators

NCP1117, NCP1117I, NCV1117



SOT−223
ST SUFFIX
CASE 318H



DPAK
DT SUFFIX
CASE 369C

The NCP1117 series are low dropout positive voltage regulators that are capable of providing an output current that is in excess of 1.0 A with a maximum dropout voltage of 1.2 V at 800 mA over temperature. This series contains nine fixed output voltages of 1.5 V, 1.8 V, 1.9 V, 2.0 V, 2.5 V, 2.85 V, 3.3 V, 5.0 V, and 12 V that have no minimum load requirement to maintain regulation. Also included is an adjustable output version that can be programmed from 1.25 V to 18.8 V with two external resistors. On chip trimming adjusts the reference/output voltage to within ±1.0% accuracy. Internal protection features consist of output current limiting, safe operating area compensation, and thermal shutdown. The NCP1117 series can operate with up to 20 V input. Devices are available in SOT−223 and DPAK packages.

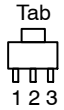
Features

- Output Current in Excess of 1.0 A
- 1.2 V Maximum Dropout Voltage at 800 mA Over Temperature
- Fixed Output Voltages of 1.5 V, 1.8 V, 1.9 V, 2.0 V, 2.5 V, 2.85 V, 3.3 V, 5.0 V, and 12 V
- Adjustable Output Voltage Option
- No Minimum Load Requirement for Fixed Voltage Output Devices
- Reference/Output Voltage Trimmed to ±1.0%
- Current Limit, Safe Operating and Thermal Shutdown Protection
- Operation to 20 V Input
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

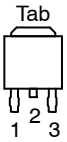
Applications

- Consumer and Industrial Equipment Point of Regulation
- Active SCSI Termination for 2.85 V Version
- Switching Power Supply Post Regulation
- Hard Drive Controllers
- Battery Chargers

PIN CONFIGURATION



SOT−223
(Top View)



DPAK
(Top View)

Pin: 1. Adjust/Ground
2. Output
3. Input

Heatsink tab is connected to Pin 2.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 14 of this data sheet.

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TYPICAL APPLICATIONS

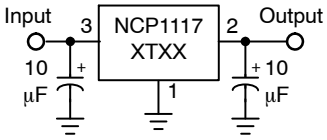


Figure 1. Fixed Output Regulator

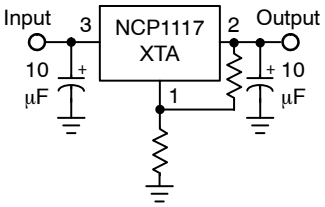


Figure 2. Adjustable Output Regulator

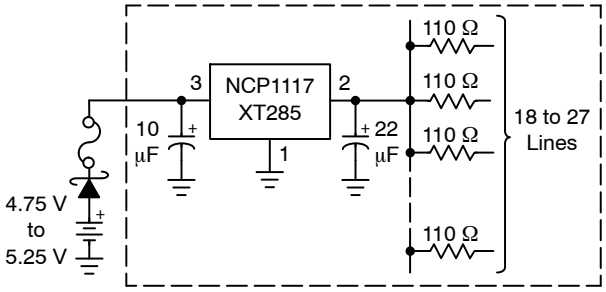


Figure 3. Active SCSI Bus Terminator

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V_{in}	20	V
Output Short Circuit Duration (Notes 2 and 3)	–	Infinite	–
Power Dissipation and Thermal Characteristics Case 318H (SOT−223) Power Dissipation (Note 2) Thermal Resistance, Junction−to−Ambient, Minimum Size Pad Thermal Resistance, Junction−to−Case Case 369A (DPAK) Power Dissipation (Note 2) Thermal Resistance, Junction−to−Ambient, Minimum Size Pad Thermal Resistance, Junction−to−Case	 P_D $R_{\theta JA}$ $R_{\theta JC}$ P_D $R_{\theta JA}$ $R_{\theta JC}$	 Internally Limited 160 15 Internally Limited 67 6.0	 W °C/W °C/W W °C/W °C/W
Maximum Die Junction Temperature Range	T_J	−55 to 150	°C
Storage Temperature Range	T_{stg}	−65 to 150	°C
Operating Ambient Temperature Range NCP1117 NCP1117I NCV1117	T_A	 0 to +125 −40 to +125 −40 to +125	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. This device series contains ESD protection and exceeds the following tests:
   Human Body Model (HBM), Class 2, 2000 V
   Machine Model (MM), Class B, 200 V
   Charge Device Model (CDM), Class IV, 2000 V.
2. Internal thermal shutdown protection limits the die temperature to approximately 175°C. Proper heatsinking is required to prevent activation.
   The maximum package power dissipation is: $$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$
3. The regulator output current must not exceed 1.0 A with V_{in} greater than 12 V.

ELECTRICAL CHARACTERISTICS

(C_{in} = 10 μF, C_{out} = 10 μF, for typical value T_A = 25°C, for min and max values T_A is the operating ambient temperature range that applies unless otherwise noted.) (Note 4)

Characteristic	Symbol	Min	Typ	Max	Unit
Reference Voltage, Adjustable Output Devices	V_{ref}				V
(V_{in}–V_{out} = 2.0 V, I_{out} = 10 mA, T_A = 25°C)		1.238	1.25	1.262	
(V_{in}–V_{out} = 1.4 V to 10 V, I_{out} = 10 mA to 800 mA) (Note 4)		1.225	–	1.270	
Output Voltage, Fixed Output Devices	V_{out}				V
1.5 V (V_{in} = 3.5 V, I_{out} = 10 mA, T_A = 25 °C)		1.485	1.500	1.515	
(V_{in} = 2.9 V to 11.5 V, I_{out} = 0 mA to 800 mA) (Note 4)		1.470	–	1.530	
1.8 V (V_{in} = 3.8 V, I_{out} = 10 mA, T_A = 25 °C)		1.782	1.800	1.818	
(V_{in} = 3.2 V to 11.8 V, I_{out} = 0 mA to 800 mA) (Note 4)		1.755	–	1.845	
1.9 V (V_{in} = 3.9 V, I_{out} = 10 mA, T_A = 25 °C)		1.872	1.900	1.929	
(V_{in} = 3.3 V to 11.9 V, I_{out} = 0 mA to 800 mA) (Note 4)		1.862	1.900	1.938	
2.0 V (V_{in} = 4.0 V, I_{out} = 10 mA, T_A = 25 °C)		1.970	2.000	2.030	
(V_{in} = 3.4 V to 12 V, I_{out} = 0 mA to 800 mA) (Note 4)		1.960	–	2.040	
2.5 V (V_{in} = 4.5 V, I_{out} = 10 mA, T_A = 25 °C)		2.475	2.500	2.525	
(V_{in} = 3.9 V to 10 V, I_{out} = 0 mA to 800 mA,) (Note 4)		2.450	–	2.550	
2.85 V (V_{in} = 4.85 V, I_{out} = 10 mA, T_A = 25 °C)		2.821	2.850	2.879	
(V_{in} = 4.25 V to 10 V, I_{out} = 0 mA to 800 mA) (Note 4)		2.790	–	2.910	
(V_{in} = 4.0 V, I_{out} = 0 mA to 500 mA) (Note 4)		2.790	–	2.910	
3.3 V (V_{in} = 5.3 V, I_{out} = 10 mA, T_A = 25 °C)		3.267	3.300	3.333	
(V_{in} = 4.75 V to 10 V, I_{out} = 0 mA to 800 mA) (Note 4)		3.235	–	3.365	
5.0 V (V_{in} = 7.0 V, I_{out} = 10 mA, T_A = 25 °C)		4.950	5.000	5.050	
(V_{in} = 6.5 V to 12 V, I_{out} = 0 mA to 800 mA) (Note 4)		4.900	–	5.100	
12 V (V_{in} = 14 V, I_{out} = 10 mA, T_A = 25 °C)		11.880	12.000	12.120	
(V_{in} = 13.5 V to 20 V, I_{out} = 0 mA to 800 mA) (Note 4)		11.760	–	12.240	
Line Regulation (Note 5) Adjustable (V_{in} = 2.75 V to 16.25 V, I_{out} = 10 mA)	Reg_{line}	–	0.04	0.1	%
1.5 V (V_{in} = 2.9 V to 11.5 V, I_{out} = 0 mA)		–	0.3	1.0	mV
1.8 V (V_{in} = 3.2 V to 11.8 V, I_{out} = 0 mA)		–	0.4	1.0	
1.9 V (V_{in} = 3.3 V to 11.9 V, I_{out} = 0 mA)		–	0.5	2.5	
2.0 V (V_{in} = 3.4 V to 12 V, I_{out} = 0 mA)		–	0.5	2.5	
2.5 V (V_{in} = 3.9 V to 10 V, I_{out} = 0 mA)		–	0.5	2.5	
2.85 V (V_{in} = 4.25 V to 10 V, I_{out} = 0 mA)		–	0.8	3.0	
3.3 V (V_{in} = 4.75 V to 15 V, I_{out} = 0 mA)		–	0.8	4.5	
5.0 V (V_{in} = 6.5 V to 15 V, I_{out} = 0 mA)		–	0.9	6.0	
12 V (V_{in} = 13.5 V to 20 V, I_{out} = 0 mA)		–	1.0	7.5	
Load Regulation (Note 5) Adjustable (I_{out} = 10 mA to 800 mA, V_{in} = 4.25 V)	Reg_{line}	–	0.2	0.4	%
1.5 V (I_{out} = 0 mA to 800 mA, V_{in} = 2.9 V)		–	2.3	5.5	mV
1.8 V (I_{out} = 0 mA to 800 mA, V_{in} = 3.2 V)		–	2.6	6.0	
1.9 V (I_{out} = 0 mA to 800 mA, V_{in} = 3.3 V)		–	2.7	6.0	
2.0 V (I_{out} = 0 mA to 800 mA, V_{in} = 3.4 V)		–	3.0	6.0	
2.5 V (I_{out} = 0 mA to 800 mA, V_{in} = 3.9 V)		–	3.3	7.5	
2.85 V (I_{out} = 0 mA to 800 mA, V_{in} = 4.25 V)		–	3.8	8.0	
3.3 V (I_{out} = 0 mA to 800 mA, V_{in} = 4.75 V)		–	4.3	10	
5.0 V (I_{out} = 0 mA to 800 mA, V_{in} = 6.5 V)		–	6.7	15	
12 V (I_{out} = 0 mA to 800 mA, V_{in} = 13.5 V)		–	16	28	
Dropout Voltage (Measured at V_{out} – 100 mV)	V_{in}–V_{out}				V
(I_{out} = 100 mA)		–	0.95	1.10	
(I_{out} = 500 mA)		–	1.01	1.15	
(I_{out} = 800 mA)		–	1.07	1.20	
Output Current Limit (V_{in}–V_{out} = 5.0 V, T_A = 25°C, Note 6)	I_{out}	1000	1500	2200	mA
Minimum Required Load Current for Regulation, Adjustable Output Devices (V_{in} = 15 V)	$I_{L(min)}$	–	0.8	5.0	mA

ELECTRICAL CHARACTERISTICS (continued)
(C_{in} = 10 μF, C_{out} = 10 μF, for typical value T_A = 25°C, for min and max values T_A is the operating ambient temperature range that applies unless otherwise noted.) (Note 4)

Characteristic	Symbol	Min	Typ	Max	Unit
Quiescent Current	I_Q				mA
1.5 V (V_{in} = 11.5 V)		–	3.6	10	
1.8 V (V_{in} = 11.8 V)		–	4.2	10	
1.9 V (V_{in} = 11.9 V)		–	4.3	10	
2.0 V (V_{in} = 12 V)		–	4.5	10	
2.5 V (V_{in} = 10 V)		–	5.2	10	
2.85 V (V_{in} = 10 V)		–	5.5	10	
3.3 V (V_{in} = 15 V)		–	6.0	10	
5.0 V (V_{in} = 15 V)		–	6.0	10	
12 V (V_{in} = 20 V)		–	6.0	10	
Thermal Regulation (T_A = 25°C, 30 ms Pulse)		–	0.01	0.1	%/W
Ripple Rejection (V_{in}–V_{out} = 6.4 V, I_{out} = 500 mA, 10 V_{pp} 120 Hz Sinewave)	RR				dB
Adjustable		67	73	–	
1.5 V		66	72	–	
1.8 V		66	70	–	
1.9 V		66	72	–	
2.0 V		64	70	–	
2.5 V		62	68	–	
2.85 V		62	68	–	
3.3 V		60	64	–	
5.0 V		57	61	–	
12 V		50	54	–	
Adjustment Pin Current (V_{in} = 11.25 V, I_{out} = 800 mA)	I_{adj}	–	52	120	μA
Adjust Pin Current Change (V_{in}–V_{out} = 1.4 V to 10 V, I_{out} = 10 mA to 800 mA)	ΔI_{adj}	–	0.4	5.0	μA
Temperature Stability	S_T	–	0.5	–	%
Long Term Stability (T_A = 25°C, 1000 Hrs End Point Measurement)	S_t	–	0.3	–	%
RMS Output Noise (f = 10 Hz to 10 kHz)	N	–	0.003	–	$\%V_{out}$

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. NCP1117: T_{low} = 0°C, T_{high} = 125°C
   NCP1117I: T_{low} = −40°C, T_{high} = 125°C
   NCV1117: T_{low} = −40°C, T_{high} = 125°C
5. Low duty cycle pulse techniques are used during testing to maintain the junction temperature as close to ambient as possible.
6. The regulator output current must not exceed 1.0 A with V_{in} greater than 12 V.

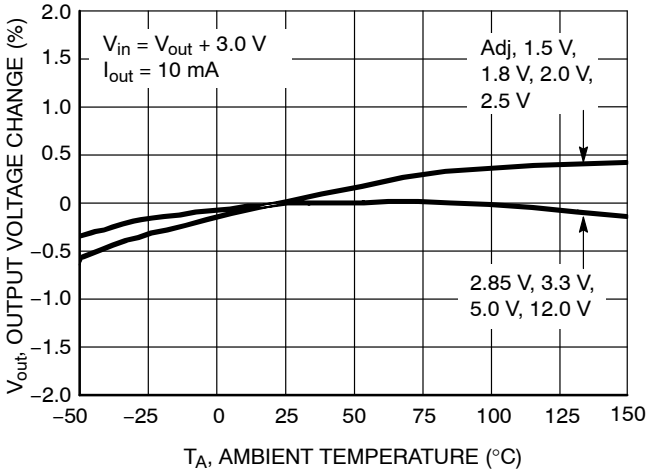


Figure 4. Output Voltage Change vs. Temperature

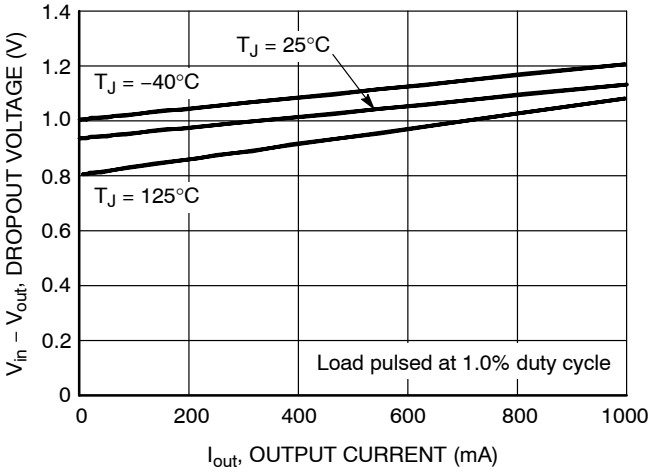


Figure 5. Dropout Voltage vs. Output Current

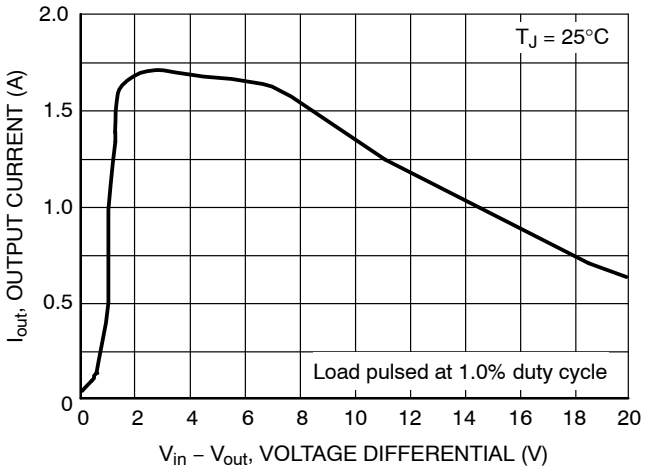


Figure 6. Output Short Circuit Current vs. Differential Voltage

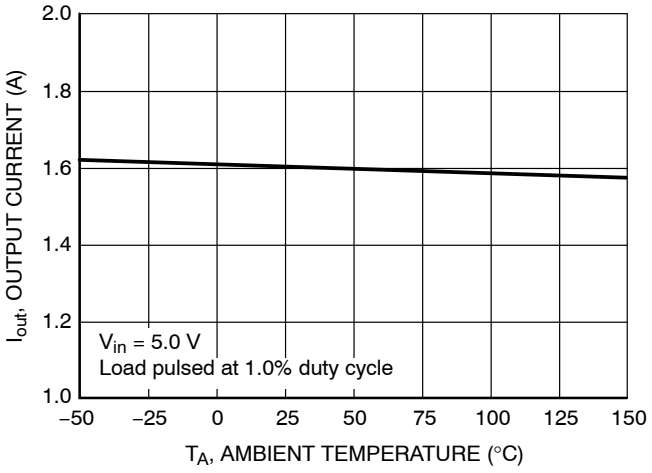


Figure 7. Output Short Circuit Current vs. Temperature

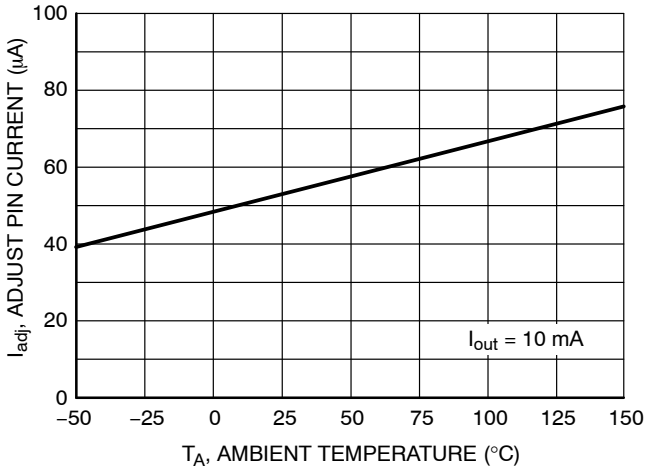


Figure 8. Adjust Pin Current vs. Temperature

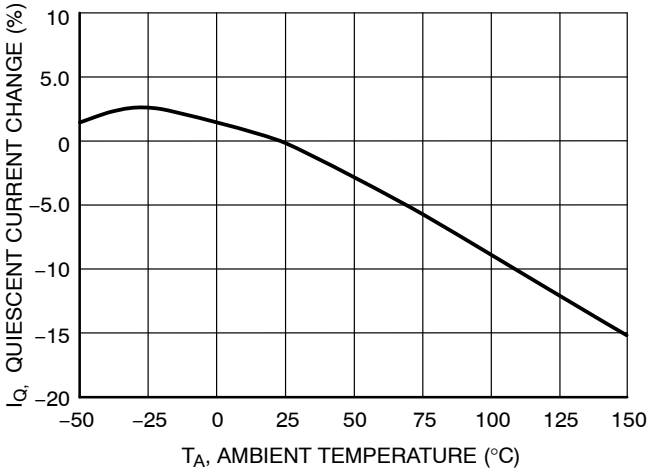


Figure 9. Quiescent Current Change vs. Temperature

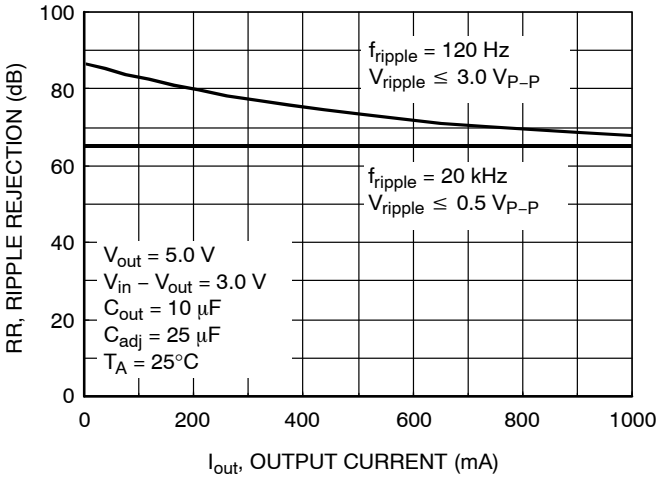


Figure 10. NCP1117XTA Ripple Rejection vs. Output Current

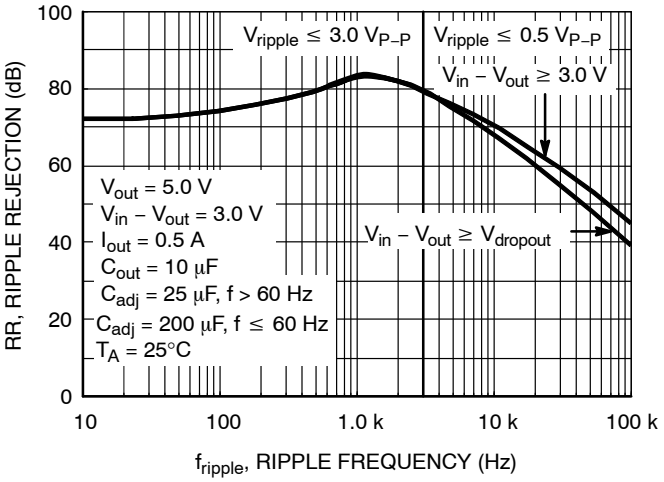


Figure 11. NCP1117XTA Ripple Rejection vs. Frequency

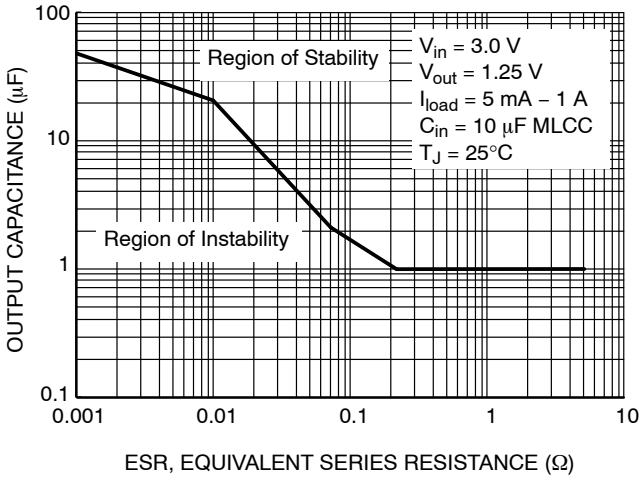


Figure 12. Output Capacitance vs. ESR

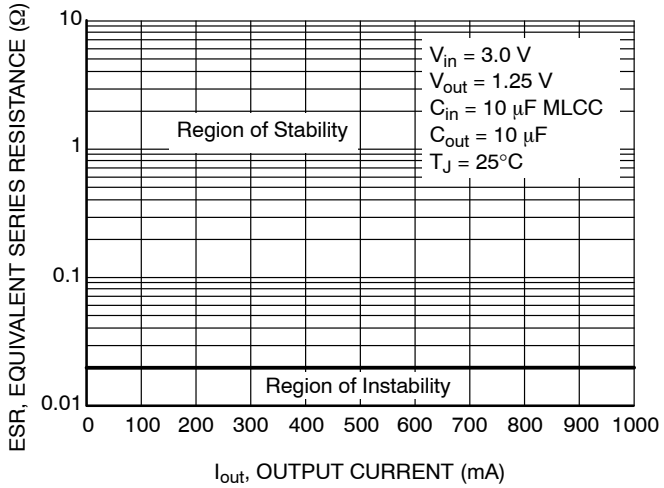


Figure 13. Typical ESR vs. Output Current

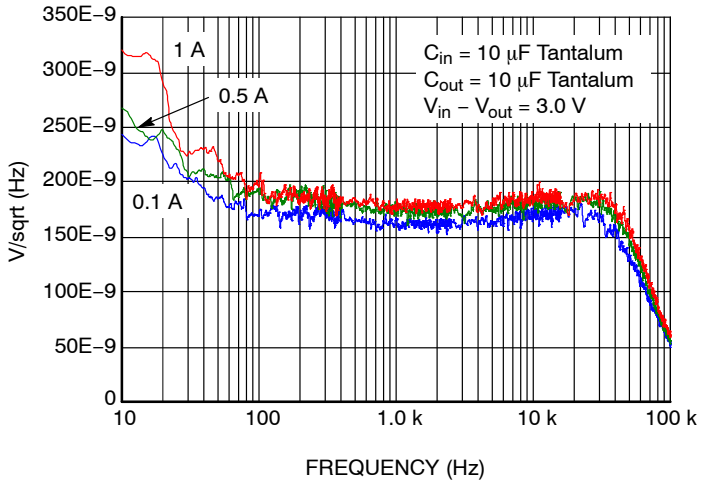


Figure 14. Output Spectral Noise Density vs. Frequency, V_{out} = 1V5

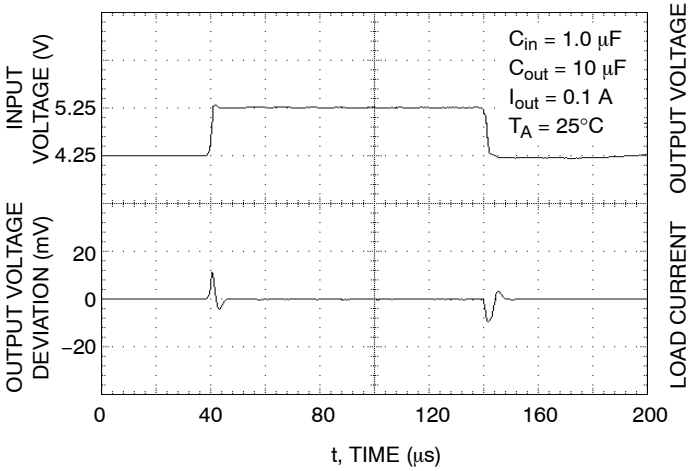


Figure 15. NCP1117XT285 Line Transient Response

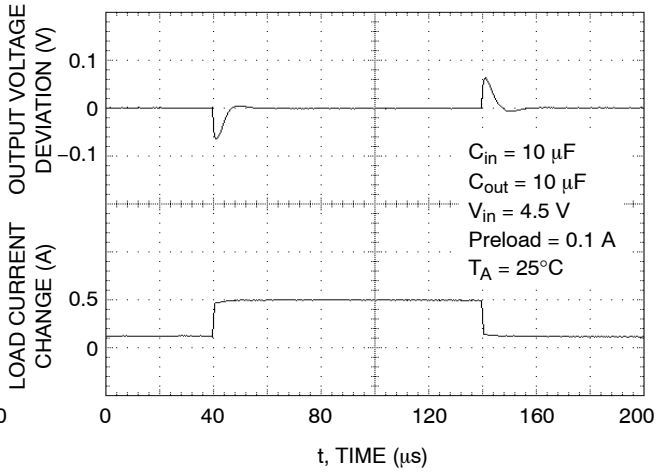


Figure 16. NCP1117XT285 Load Transient Response

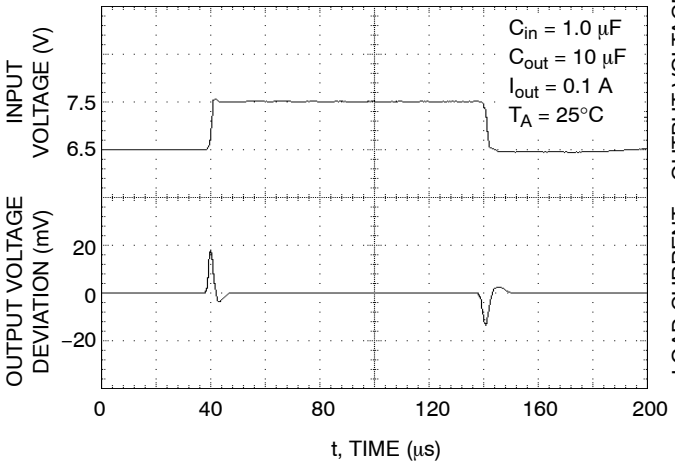


Figure 17. NCP1117XT50 Line Transient Response

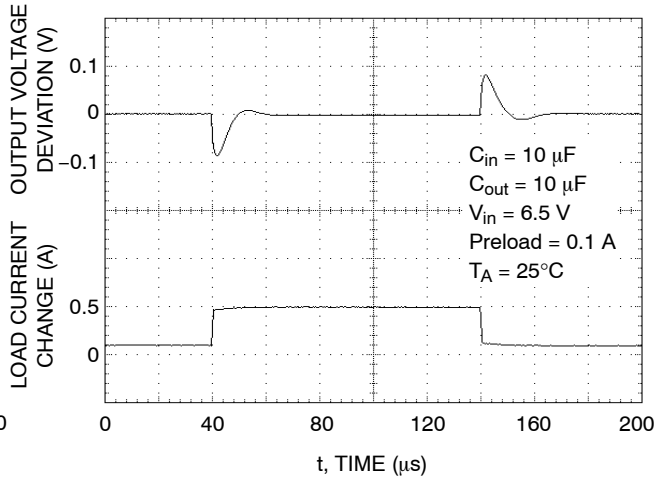


Figure 18. NCP1117XT50 Load Transient Response

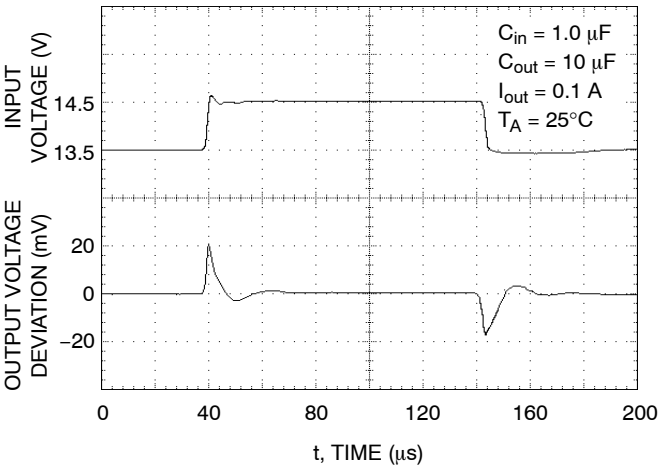


Figure 19. NCP1117XT12 Line Transient Response

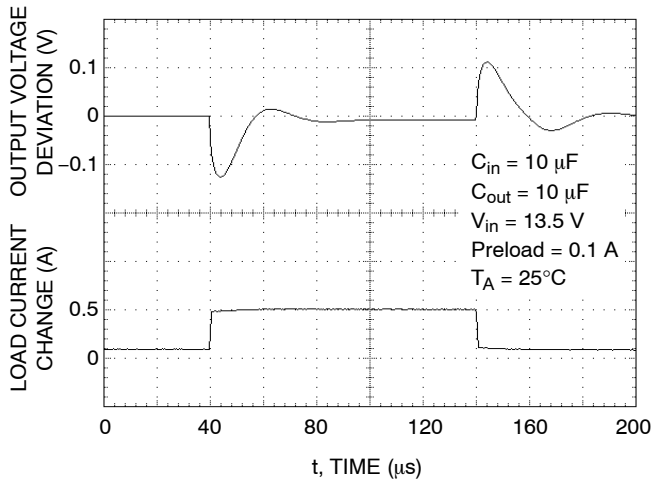


Figure 20. NCP1117XT12 Load Transient Response

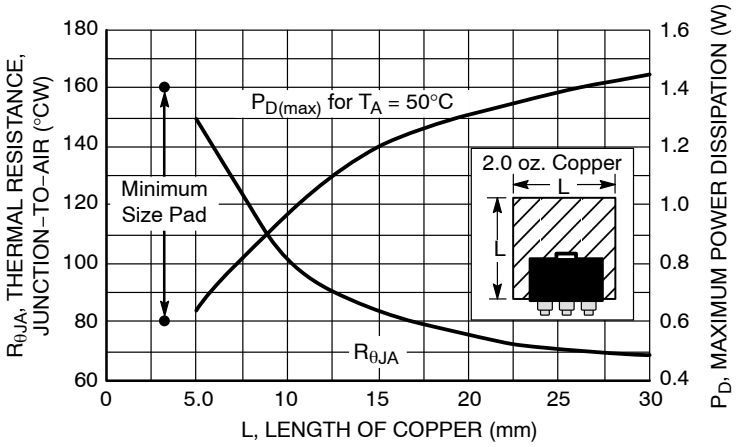


Figure 21. SOT−223 Thermal Resistance and Maximum Power Dissipation vs. P.C.B. Copper Length

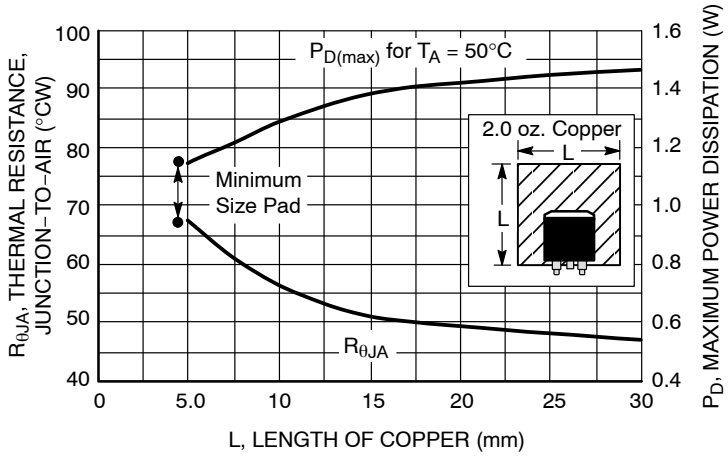


Figure 22. DPAK Thermal Resistance and Maximum Power Dissipation vs. P.C.B. Copper Length

APPLICATIONS INFORMATION

Introduction

The NCP1117 features a significant reduction in dropout voltage along with enhanced output voltage accuracy and temperature stability when compared to older industry standard three−terminal adjustable regulators. These devices contain output current limiting, safe operating area compensation and thermal shutdown protection making them designer friendly for powering numerous consumer and industrial products. The NCP1117 series is pin compatible with the older LM317 and its derivative device types.

Output Voltage

The typical application circuits for the fixed and adjustable output regulators are shown in Figures 23 and 24. The adjustable devices are floating voltage regulators. They develop and maintain the nominal 1.25 V reference voltage between the output and adjust pins. The reference voltage is programmed to a constant current source by resistor R1, and this current flows through R2 to ground to set the output voltage. The programmed current level is usually selected to be greater than the specified 5.0 mA minimum that is required for regulation. Since the adjust pin current, I_{adj}, is significantly lower and constant with respect to the programmed load current, it generates a small output voltage error that can usually be ignored. For the fixed output devices R1 and R2 are included within the device and the ground current I_{gnd}, ranges from 3.0 mA to 5.0 mA depending upon the output voltage.

External Capacitors

Input bypass capacitor C_{in} may be required for regulator stability if the device is located more than a few inches from the power source. This capacitor will reduce the circuit's sensitivity when powered from a complex source impedance and significantly enhance the output transient response. The input bypass capacitor should be mounted with the shortest possible track length directly across the regulator's input and ground terminals. A 10 μF ceramic or tantalum capacitor should be adequate for most applications.

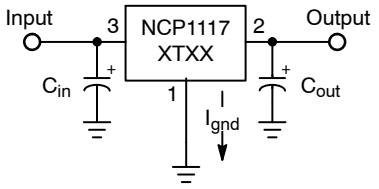
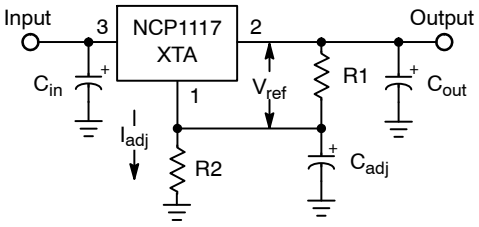


Figure 23. Fixed Output Regulator

Frequency compensation for the regulator is provided by capacitor C_{out} and its use is mandatory to ensure output stability. A minimum capacitance value of 4.7 μF with an equivalent series resistance (ESR) that is within the limits of 33 mΩ (typ) to 2.2 Ω is required. See Figures 12 and 13. The capacitor type can be ceramic, tantalum, or aluminum electrolytic as long as it meets the minimum capacitance value and ESR limits over the circuit's entire operating temperature range. Higher values of output capacitance can be used to enhance loop stability and transient response with the additional benefit of reducing output noise.



$$V_{out} = V_{ref}\left(1 + \frac{R2}{R1}\right) + I_{adj}\,R2$$

Figure 24. Adjustable Output Regulator

The output ripple will increase linearly for fixed and adjustable devices as the ratio of output voltage to the reference voltage increases. For example, with a 12 V regulator, the output ripple will increase by 12 V/1.25 V or 9.6 and the ripple rejection will decrease by 20 log of this ratio or 19.6 dB. The loss of ripple rejection can be restored to the values shown with the addition of bypass capacitor C_{adj}, shown in Figure 24. The reactance of C_{adj} at the ripple frequency must be less than the resistance of R1. The value of R1 can be selected to provide the minimum required load current to maintain regulation and is usually in the range of 100 Ω to 200 Ω.

$$C_{adj} > \frac{1}{2\,\pi\,f_{ripple}\,R1}$$

The minimum required capacitance can be calculated from the above formula. When using the device in an application that is powered from the AC line via a transformer and a full wave bridge, the value for C_{adj} is:

$$f_{ripple} = 120\ Hz,\ R1 = 120\ \Omega,\ \text{then}\ C_{adj} > 11.1\ \mu F$$

The value for C_{adj} is significantly reduced in applications where the input ripple frequency is high. If used as a post regulator in a switching converter under the following conditions:

$$f_{ripple} = 50\ kHz,\ R1 = 120\ \Omega,\ \text{then}\ C_{adj} > 0.027\ \mu F$$

Figures 10 and 11 shows the level of ripple rejection that is obtainable with the adjust pin properly bypassed.

Protection Diodes

The NCP1117 family has two internal low impedance diode paths that normally do not require protection when used in the typical regulator applications. The first path connects between V_{out} and V_{in}, and it can withstand a peak surge current of about 15 A. Normal cycling of V_{in} cannot generate a current surge of this magnitude. Only when V_{in} is shorted or crowbarred to ground and C_{out} is greater than 50 μF, it becomes possible for device damage to occur. Under these conditions, diode D1 is required to protect the device. The second path connects between C_{adj} and V_{out}, and it can withstand a peak surge current of about 150 mA. Protection diode D2 is required if the output is shorted or crowbarred to ground and C_{adj} is greater than 1.0 μF.

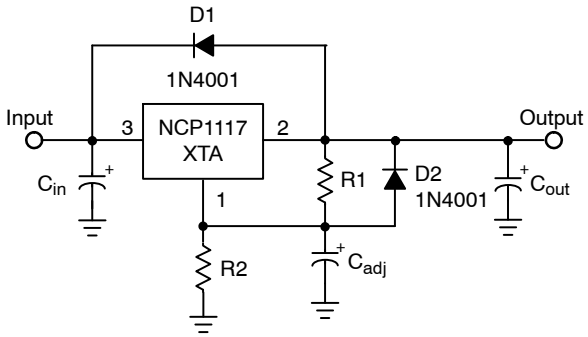


Figure 25. Protection Diode Placement

A combination of protection diodes D1 and D2 may be required in the event that V_{in} is shorted to ground and C_{adj} is greater than 50 μF. The peak current capability stated for the internal diodes are for a time of 100 μs with a junction temperature of 25°C. These values may vary and are to be used as a general guide.

Load Regulation

The NCP1117 series is capable of providing excellent load regulation; but since these are three terminal devices, only partial remote load sensing is possible. There are two conditions that must be met to achieve the maximum available load regulation performance. The first is that the top side of programming resistor R1 should be connected as close to the regulator case as practicable. This will minimize the voltage drop caused by wiring resistance RW + from appearing in series with reference voltage that is across R1.

The second condition is that the ground end of R2 should be connected directly to the load. This allows true Kelvin sensing where the regulator compensates for the voltage drop caused by wiring resistance RW −.

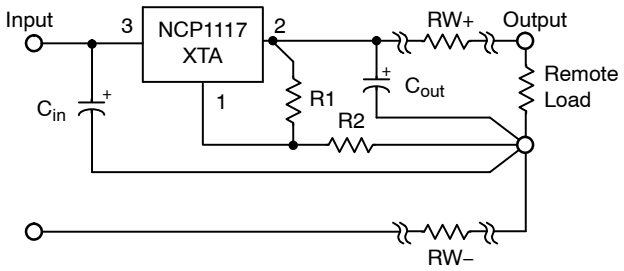


Figure 26. Load Sensing

Thermal Considerations

This series contains an internal thermal limiting circuit that is designed to protect the regulator in the event that the maximum junction temperature is exceeded. When activated, typically at 175°C, the regulator output switches off and then back on as the die cools. As a result, if the device is continuously operated in an overheated condition, the output will appear to be oscillating. This feature provides protection from a catastrophic device failure due to accidental overheating. It is not intended to be used as a substitute for proper heatsinking. The maximum device power dissipation can be calculated by:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The devices are available in surface mount SOT−223 and DPAK packages. Each package has an exposed metal tab that is specifically designed to reduce the junction to air thermal resistance, $R_{\theta JA}$, by utilizing the printed circuit board copper as a heat dissipater. Figures 21 and 22 show typical $R_{\theta JA}$ values that can be obtained from a square pattern using economical single sided 2.0 ounce copper board material. The final product thermal limits should be tested and quantified in order to insure acceptable performance and reliability. The actual $R_{\theta JA}$ can vary considerably from the graphs shown. This will be due to any changes made in the copper aspect ratio of the final layout, adjacent heat sources, and air flow.

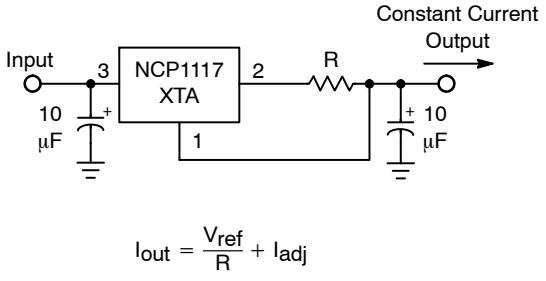


Figure 27. Constant Current Regulator

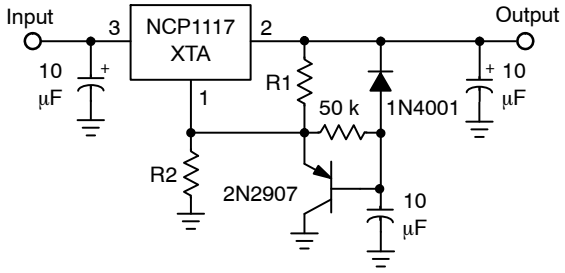


Figure 28. Slow Turn−On Regulator

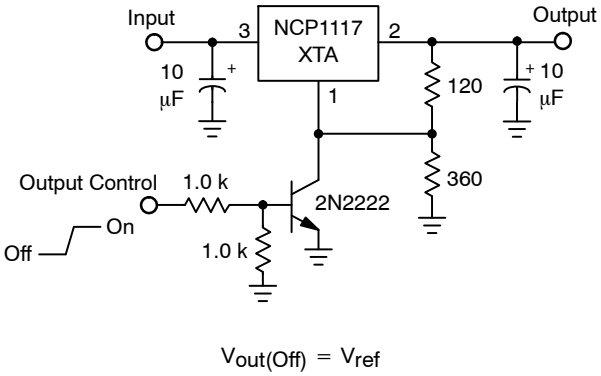
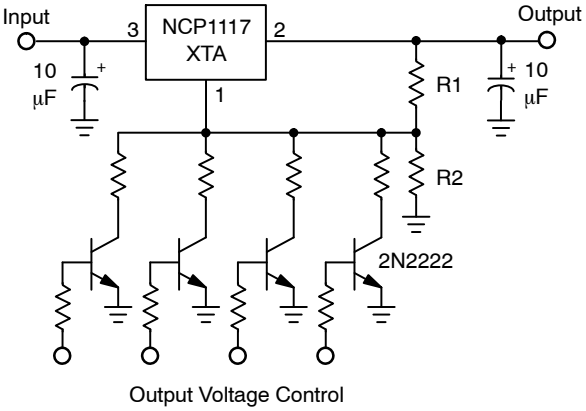
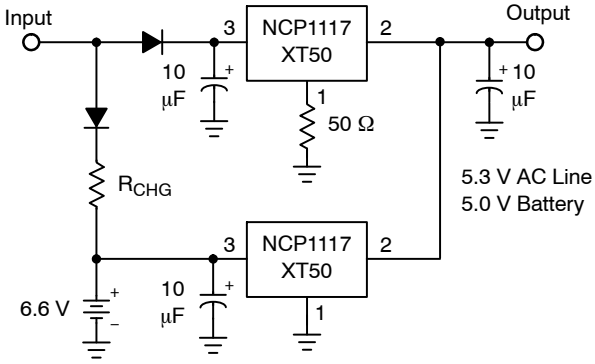


Figure 29. Regulator with Shutdown



Resistor R2 sets the maximum output voltage. Each transistor reduces the output voltage when turned on.

Figure 30. Digitally Controlled Regulator



The 50 Ω resistor that is in series with the ground pin of the upper regulator level shifts its output 300 mV higher than the lower regulator. This keeps the lower regulator off until the input source is removed.

Figure 31. Battery Backed−Up Power Supply

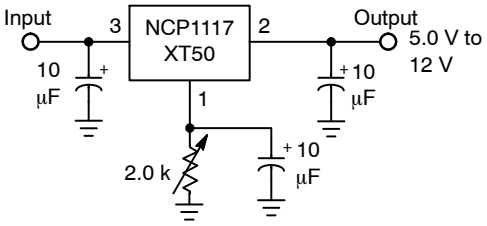


Figure 32. Adjusting Output of Fixed Voltage Regulators

ORDERING INFORMATION – (NCP1117)

Device	Nominal Output Voltage	Package	Shipping†
NCP1117STAT3G	Adjustable	SOT−223 (Pb−Free)	4000 / Tape & Reel
NCP1117ST15T3G	1.5		
NCP1117ST18T3G	1.8		
NCP1117ST20T3G	2.0		
NCP1117ST25T3G	2.5		
NCP1117ST33T3G	3.3		
NCP1117ST50T3G	5.0		
NCP1117ST12T3G	12		
NCP1117DTAG	Adjustable	DPAK (Pb−Free)	75 Units / Rail
NCP1117DTARKG	Adjustable		2500 / Tape & Reel
NCP1117DTAT5G	Adjustable		2500 / Tape & Reel
NCP1117DT15G	1.5		75 Units / Rail
NCP1117DT15RKG	1.5		2500 / Tape & Reel
NCP1117DT18G	1.8		75 Units / Rail
NCP1117DT18RKG	1.8		2500 / Tape & Reel
NCP1117DT18T5G	1.8		2500 / Tape & Reel
NCP1117DT19RKG	1.9		2500 / Tape & Reel
NCP1117DT20G	2.0		75 Units / Rail
NCP1117DT20RKG	2.0		2500 / Tape & Reel
NCP1117DT25G	2.5		75 Units / Rail
NCP1117DT25RKG	2.5		2500 / Tape & Reel
NCP1117DT25T5G	2.5		2500 / Tape & Reel
NCP1117DT285G	2.85		75 Units / Rail
NCP1117DT285RKG	2.85		2500 / Tape & Reel
NCP1117DT33G	3.3		75 Units / Rail
NCP1117DT33RKG	3.3		2500 / Tape & Reel
NCP1117DT33T5G	3.3		2500 / Tape & Reel
NCP1117DT50G	5.0		75 Units / Rail
NCP1117DT50RKG	5.0		2500 / Tape & Reel
NCP1117DT12G	12		75 Units / Rail
NCP1117DT12RKG	12		2500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ORDERING INFORMATION – (NCP1117I)

Device	Nominal Output Voltage	Package	Shipping†
NCP1117ISTAT3G	Adjustable	SOT−223 (Pb−Free)	4000 / Tape & Reel
NCP1117IST18T3G	1.8		
NCP1117IST33T3G	3.3		
NCP1117IST50T3G	5.0		
NCP1117IDTAT4G	Adjustable	DPAK (Pb−Free)	2500 / Tape & Reel
NCP1117IDT33T4G	3.3		
NCP1117IDT50T4G	5.0		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ORDERING INFORMATION – (NCV1117)

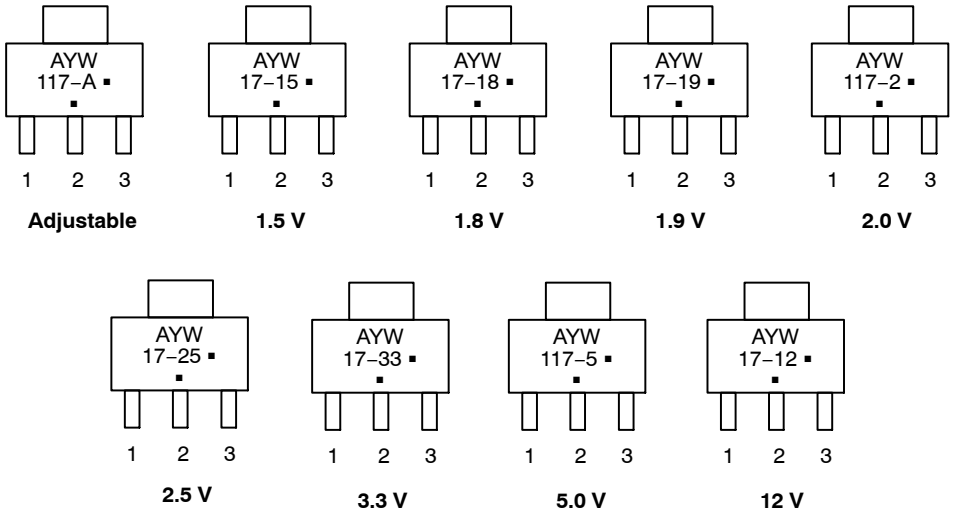
Device	Nominal Output Voltage	Package	Shipping†
NCV1117STAT3G*	Adjustable	SOT−223 (Pb−Free)	4000 / Tape & Reel
NCV1117ST15T3G*	1.5		
NCV1117ST18T3G*	1.8		
NCV1117ST20T3G*	2.0		
NCV1117ST25T3G*	2.5		
NCV1117ST33T3G*	3.3		
NCV1117ST50T3G*	5.0		
NCV1117ST12T3G*	12		
NCV1117DTARKG*	Adjustable	DPAK (Pb−Free)	2500 / Tape & Reel
NCV1117DT15RKG*	1.5		
NCV1117DT18RKG*	1.8		
NCV1117DT18T5G*	1.8		
NCV1117DT20RKG*	2.0		
NCV1117DT25RKG*	2.5		
NCV1117DT33T4G*	3.3		
NCV1117DT33T5G*	3.3		
NCV1117DT50RKG*	5.0		
NCV1117DT12RKG*	12		

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

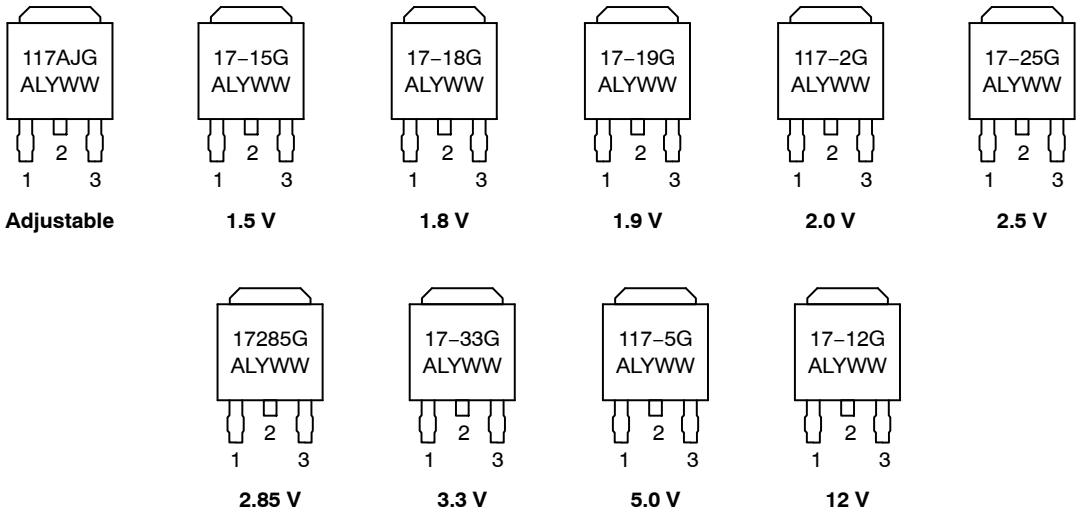
*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC−Q100 Qualified and PPAP Capable

MARKING DIAGRAMS – NCP1117

SOT−223
ST SUFFIX
CASE 318H



DPAK
DT SUFFIX
CASE 369C

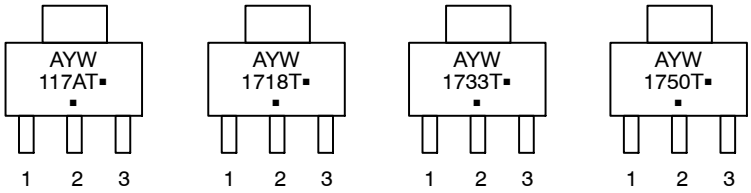


A = Assembly Location
L = Wafer Lot
Y = Year
WW, W = Work Week
▪ or G = Pb−Free Package

(Note: Microdot may be in either location)

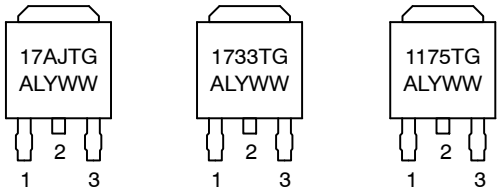
MARKING DIAGRAMS – NCP1117I

SOT−223
ST SUFFIX
CASE 318H



Adjustable **1.8 V** **3.3 V** **5.0 V**

DPAK
DT SUFFIX
CASE 369C



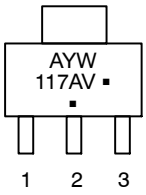
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A = Assembly Location
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WW, W = Work Week
▪ or G = Pb−Free Package

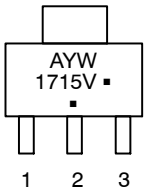
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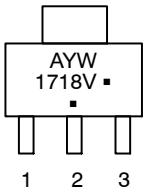
SOT−223
ST SUFFIX
CASE 318H



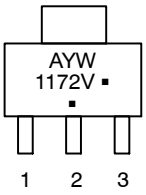
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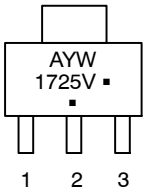
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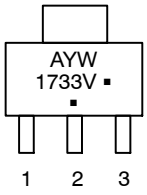
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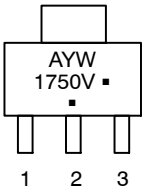
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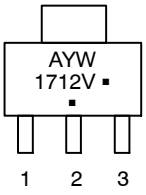
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3.3 V

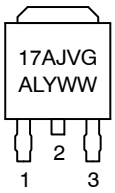


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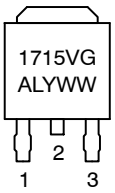


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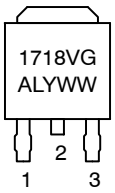
DPAK
DT SUFFIX
CASE 369C



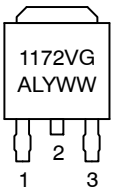
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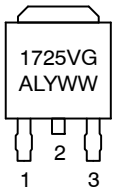
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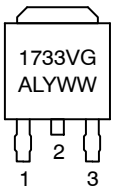
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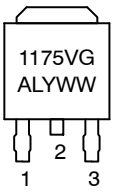
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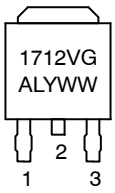
2.5 V



3.3 V



5.0 V



12 V

A = Assembly Location
L = Wafer Lot
Y = Year
WW, W = Work Week
▪ or G = Pb−Free Package

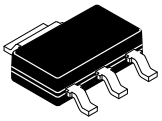
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MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

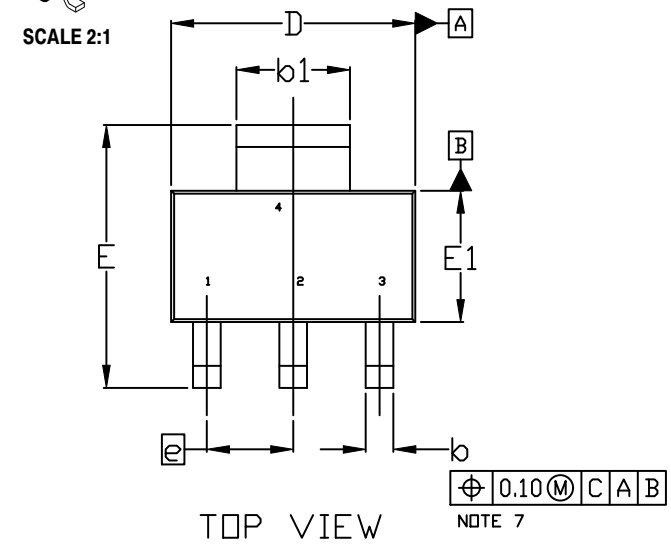
ON Semiconductor®

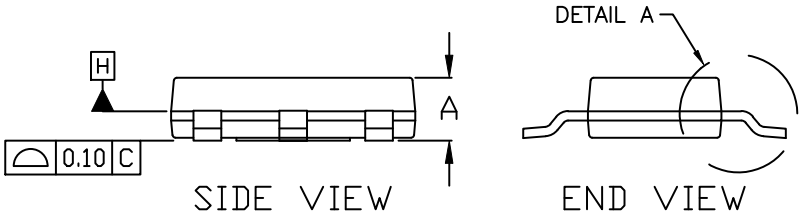
SOT−223
CASE 318H
ISSUE B

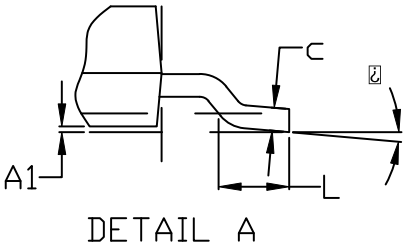
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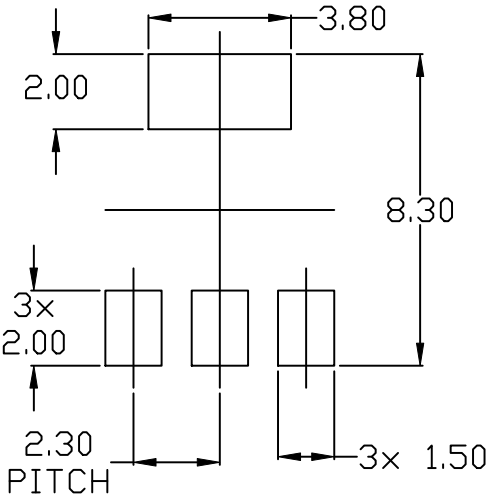






NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D & E1 ARE DETERMINED AT DATUM H. DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. SHALL NOT EXCEED 0.23mm PER SIDE.
4. LEAD DIMENSIONS b AND b1 DO NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBBAR PROTRUSION IS 0.08mm PER SIDE.
5. DATUMS A AND B ARE DETERMINED AT DATUM H.
6. A1 IS DEFINED AS THE VERTICAL DISTANCE FROM THE SEATING PLANE TO THE LOWEST POINT OF THE PACKAGE BODY.
7. POSITIONAL TOLERANCE APPLIES TO DIMENSIONS b AND b1.

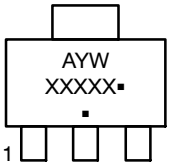
	MILLIMETERS		
DIM	MIN.	NOM.	MAX.
A	---	---	1.80
A1	0.02	0.06	0.11
b	0.60	0.74	0.88
b1	2.90	3.00	3.10
c	0.24	---	0.35
D	6.30	6.50	6.70
E	6.70	7.00	7.30
E1	3.30	3.50	3.70
e	2.30 BSC		
L	0.25	---	---
θ	0°	---	10°



RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



A = Assembly Location
Y = Year
W = Work Week
XXXXX = Specific Device Code
▪ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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DESCRIPTION:	**SOT−223**	**PAGE 1 OF 1**

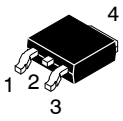
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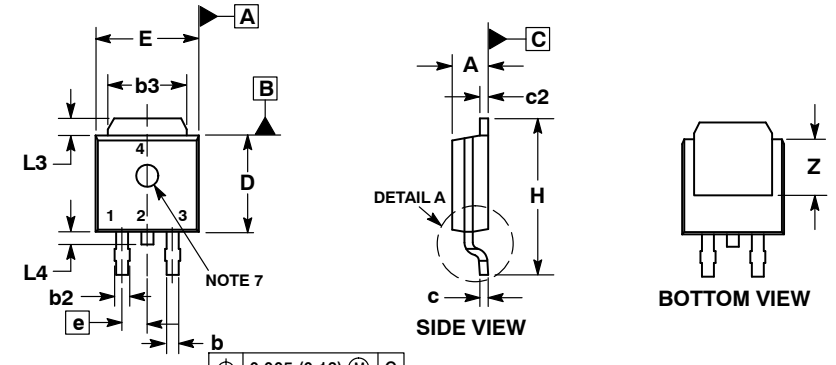
MECHANICAL CASE OUTLINE
PACKAGE DIMENSIONS

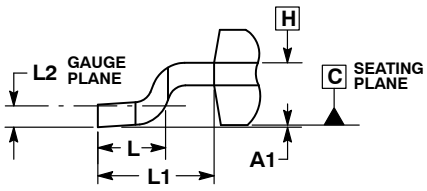
DPAK (SINGLE GAUGE)
CASE 369C
ISSUE F

DATE 21 JUL 2015

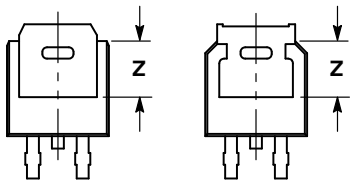


SCALE 1:1





DETAIL A
ROTATED 90° CW



BOTTOM VIEW
ALTERNATE CONSTRUCTIONS

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.
7. OPTIONAL MOLD FEATURE.

	INCHES		MILLIMETERS	
DIM	**MIN**	**MAX**	**MIN**	**MAX**
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.028	0.045	0.72	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.114 REF		2.90 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

STYLE 1:
PIN 1. BASE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 2:
PIN 1. GATE
2. DRAIN
3. SOURCE
4. DRAIN

STYLE 3:
PIN 1. ANODE
2. CATHODE
3. ANODE
4. CATHODE

STYLE 4:
PIN 1. CATHODE
2. ANODE
3. GATE
4. ANODE

STYLE 5:
PIN 1. GATE
2. ANODE
3. CATHODE
4. ANODE

STYLE 6:
PIN 1. MT1
2. MT2
3. GATE
4. MT2

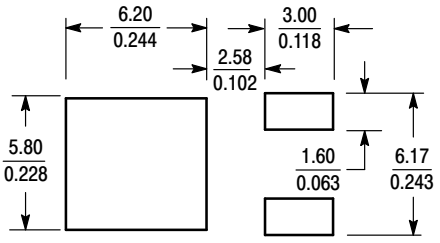
STYLE 7:
PIN 1. GATE
2. COLLECTOR
3. EMITTER
4. COLLECTOR

STYLE 8:
PIN 1. N/C
2. CATHODE
3. ANODE
4. CATHODE

STYLE 9:
PIN 1. ANODE
2. CATHODE
3. RESISTOR ADJUST
4. CATHODE

STYLE 10:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. ANODE

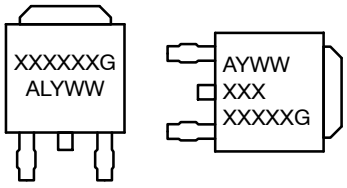
SOLDERING FOOTPRINT*



SCALE 3:1 $\left(\frac{\text{mm}}{\text{inches}}\right)$

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



IC **Discrete**

XXXXXX = Device Code
A = Assembly Location
L = Wafer Lot
Y = Year
WW = Work Week
G = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

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